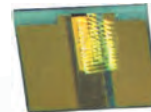


High Power RSOA Chip on Carriers



Part Number: COC-289

High Power RSOA Chip on Carrier
Single-Mode RSOA Gain Chip
Wavelength at 1310nm



Features

- High Output Power
- High Dynamic Range
- High Efficiency
- Standard RSOA Chip on Carrier
- Cost Effective

Application

- External Cavity Laser Systems
- LiDAR
- Free Space Communications
- Network Test Equipment



SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.

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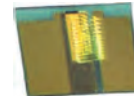
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High Power RSOA Chip on Carriers



Specification

COC-289



Optical	Symbol	Typ.	Units
Center Wavelength	λ_c	1310	nm
ASE Output Power @ 1A		0.2	Watt
Aperture Width	AW	4	μm
3dB Bandwidth	BW	80	nm
Beam Exit Angle	θ_{EXT}	19.5	Degree
Fast Axis Div.	$\theta_{\perp}$	30	Deg FWHM
Slow Axis Div.	$\theta_{\parallel}$	16	Deg FWHM
Front Facet Reflectivity		<0.1%	
Rear Face Reflectivity		98%	
Waveguide		Curved	
Electrical	Symbol		Units
Operating Current	I_{op}	1	A
Operating Voltage	V_{op}	2	V
Mechanical		Range	Units
Chip Width		500	μm
Operating Temp.**		-20 to 75	$^{\circ}\text{C}$
Storage Temp.		-40 to 85	$^{\circ}\text{C}$

*Specified values are rated at a constant heat sink temperature of 20°C.

**High temperature operation will reduce performance and MTTF.
Unless otherwise indicated all values are nominal.

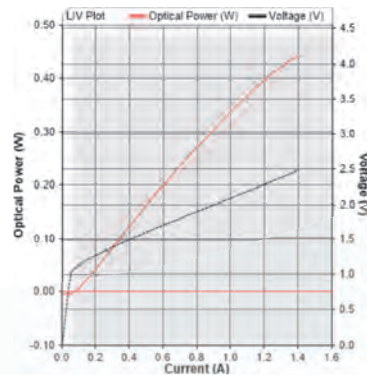
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SemiNex RSOA COC-289

Graphs & Data

Typical ASE L-I-V Characteristics



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Mechanical Drawing

